MSKSEMI 美森科













ESD

TVS

TSS

MOV

GDT

PIFD

DAN202U

Product specification

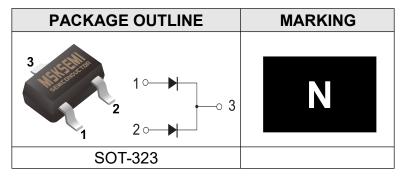




FEATURES

- Four types of packaging are available
- High speed
- Suitable for high packing density layout
- High reliability

Reference News



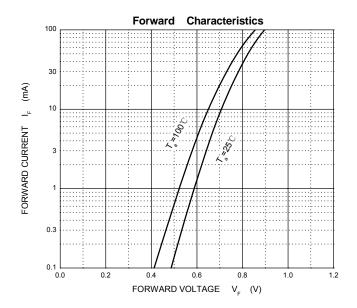
Maximum Ratings @Ta=25℃

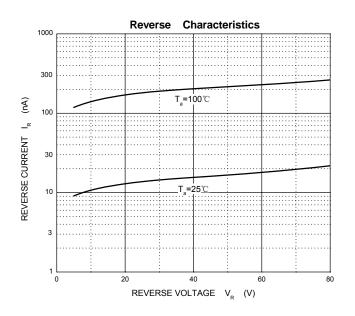
Parameter	Symbol	Limit	Unit
Non-Repetitive Peak Reverse Voltage	VRM	80	V
DC Blocking Voltage	V_{R}	80	V
Forward Continuous Current	lғм	300	mA
Non-Repetitive Peak Forward Surge Current @t=8.3ms	I _{FSM}	2.0	А
Average Rectified Output Current	lo	100	mA
Power Dissipation	PD	200	mW
Thermal resistance From Junction to ambient	$R_{ heta JA}$	625	°C/W
Operation Junction and Storage Temperature Range	T _J ,TsTG	-55~+150	℃

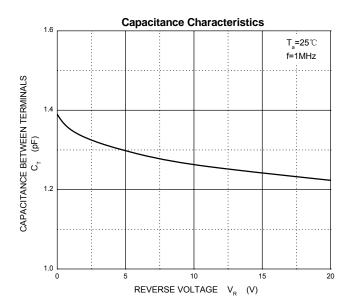
ELECTRICAL CHARACTERISTICS (Ta=25℃ unless otherwise specified)

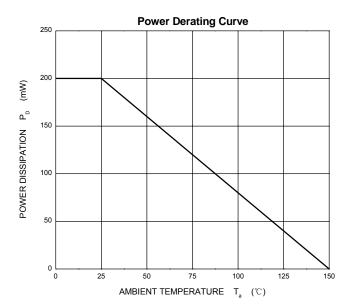
Parameter	Symbol	Test conditions	Min	Max	Unit
Reverse breakdown voltage	V _(BR)	l _R = 100μA	80		V
Reverse voltage leakage current	l _R	V _R =70V		0.1	μA
Forward voltage	VF	l==100mA		1.2	V
Diode capacitance	C _D	V _R =6V, f=1MHz		3.5	pF
Reverse recovery time	t _{rr}	V _R =6V, I _F =5mA		4	ns





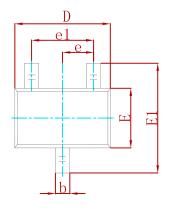


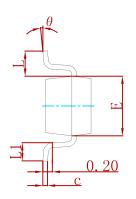


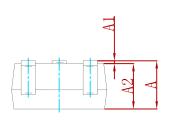




PACKAGEMECHANICALDATA

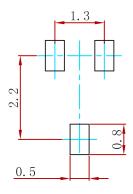






Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.200	0.400	0.008	0.016	
С	0.080	0.150	0.003	0.006	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.650 TYP		0.026 TYP		
e1	1.200	1.400	0.047	0.055	
L	0.525 REF		0.021 REF		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

Suggested Pad Layout



Note:

- 1. Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
DAN202U	SOT-323	3000



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